NSN 5961-01-020-5835

Transistor - Page 1 of 1

Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-020-5835 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.375 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 collector to base voltage/static/emitter open and 1200.0 collector to emitter voltage, dc with specified circuit between base and emitter and 1000.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 82577-928185 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**